

RJL6015DPK

Silicon N Channel MOS FET
High Speed Power Switching

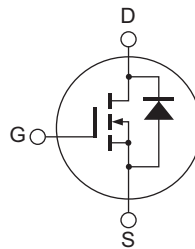
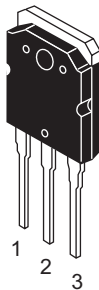
REJ03G1818-0100
Rev.1.00
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Features

- Built-in fast recovery diode
- Low on-resistance
- Low leakage current
- High speed switching

Outline

RENESAS Package code: PRSS0004ZE-A
(Package name: TO-3P)



1. Gate
2. Drain (Flange)
3. Source

Absolute Maximum Ratings

(Ta = 25°C)

| Item | Symbol | Ratings | Unit |
|---|--|-------------|------|
| Drain to source voltage | V _{DSS} | 600 | V |
| Gate to source voltage | V _{GSS} | ±30 | V |
| Drain current | I _D | 19 | A |
| Drain peak current | I _{D (pulse)} ^{Note1} | 57 | A |
| Body-drain diode reverse drain current | I _{DR} | 19 | A |
| Body-drain diode reverse drain peak current | I _{DR (pulse)} ^{Note1} | 57 | A |
| Avalanche current | I _{AP} ^{Note3} | 6 | A |
| Avalanche energy | E _{AR} ^{Note3} | 1.9 | mJ |
| Channel dissipation | P _{ch} ^{Note2} | 150 | W |
| Channel to case thermal impedance | θ _{ch-c} | 0.833 | °C/W |
| Channel temperature | T _{ch} | 150 | °C |
| Storage temperature | T _{stg} | -55 to +150 | °C |

Notes: 1. PW ≤ 10 μs, duty cycle ≤ 1%
2. Value at Tc = 25°C
3. STch = 25°C, Tch ≤ 150°C

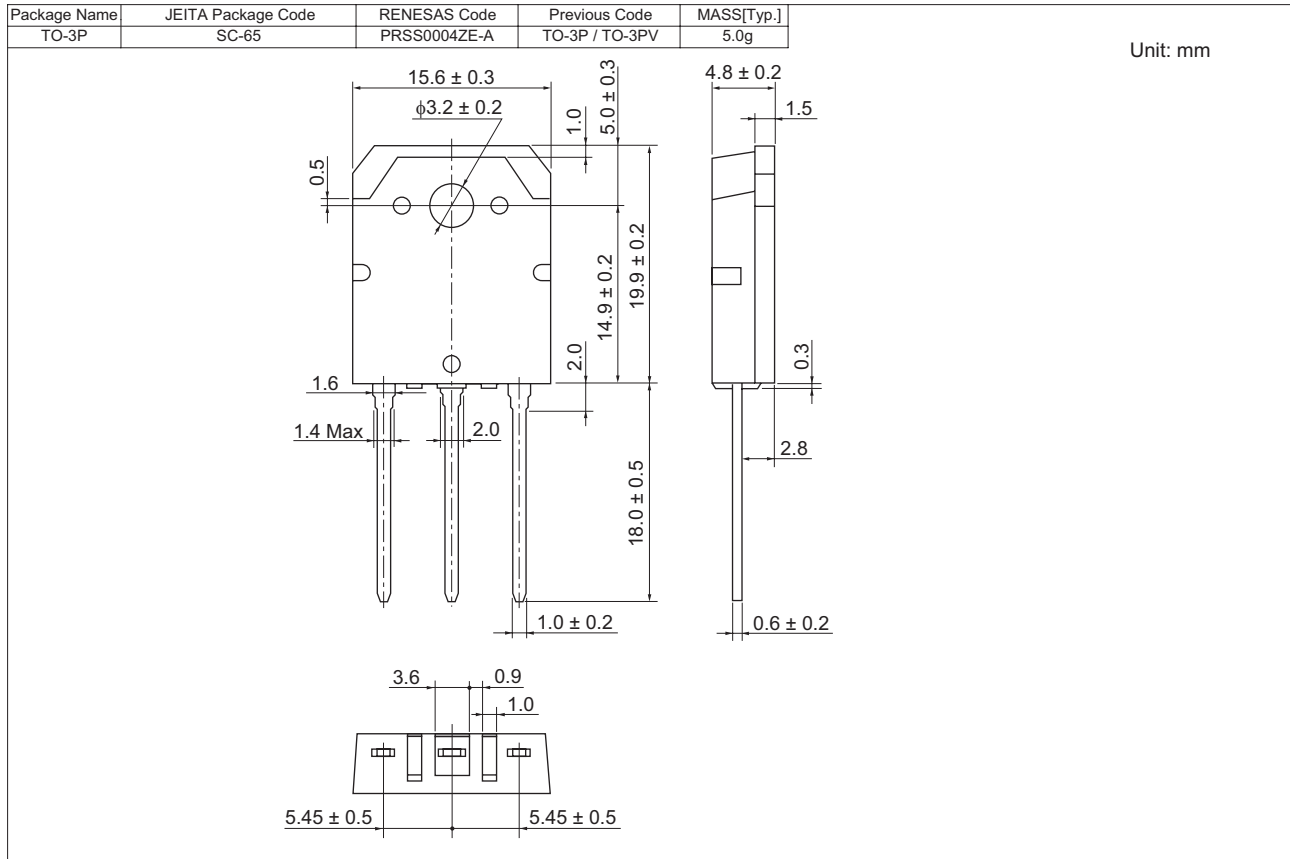
Electrical Characteristics

(Ta = 25°C)

| Item | Symbol | Min | Typ | Max | Unit | Test conditions |
|--|---------------|-----|------|-----------|---------------|--|
| Drain to source breakdown voltage | $V_{(BR)DSS}$ | 600 | — | — | V | $I_D = 10 \text{ mA}$, $V_{GS} = 0$ |
| Zero gate voltage drain current | I_{DSS} | — | — | 10 | μA | $V_{DS} = 600 \text{ V}$, $V_{GS} = 0$ |
| Gate to source leak current | I_{GSS} | — | — | ± 0.1 | μA | $V_{GS} = \pm 30 \text{ V}$, $V_{DS} = 0$ |
| Gate to source cutoff voltage | $V_{GS(off)}$ | 1.5 | — | 4.0 | V | $V_{DS} = 10 \text{ V}$, $I_D = 1 \text{ mA}$ |
| Static drain to source on state resistance | $R_{DS(on)}$ | — | 0.34 | 0.41 | Ω | $I_D = 9.5 \text{ A}$, $V_{GS} = 10 \text{ V}$ ^{Note4} |
| Input capacitance | C_{iss} | — | 2370 | — | pF | $V_{DS} = 25 \text{ V}$ |
| Output capacitance | C_{oss} | — | 242 | — | pF | $V_{GS} = 0$ |
| Reverse transfer capacitance | C_{rss} | — | 30 | — | pF | $f = 1 \text{ MHz}$ |
| Turn-on delay time | $t_{d(on)}$ | — | 35 | — | ns | $I_D = 9.5 \text{ A}$ |
| Rise time | t_r | — | 17 | — | ns | $V_{GS} = 10 \text{ V}$ |
| Turn-off delay time | $t_{d(off)}$ | — | 119 | — | ns | $R_L = 31.6 \Omega$ |
| Fall time | t_f | — | 21 | — | ns | $R_g = 10 \Omega$ |
| Total gate charge | Q_g | — | 65 | — | nC | $V_{DD} = 480 \text{ V}$ |
| Gate to source charge | Q_{gs} | — | 11.3 | — | nC | $V_{GS} = 10 \text{ V}$ |
| Gate to drain charge | Q_{gd} | — | 30.5 | — | nC | $I_D = 19 \text{ A}$ |
| Body-drain diode forward voltage | V_{DF} | — | 1.05 | 1.75 | V | $I_F = 19 \text{ A}$, $V_{GS} = 0$ ^{Note4} |
| Body-drain diode reverse recovery time | t_{rr} | — | 180 | — | ns | $I_F = 19 \text{ A}$, $V_{GS} = 0$ $di_F/dt = 100 \text{ A}/\mu\text{s}$ |

Notes: 4. Pulse test

Package Dimensions



Ordering Information

| Part No. | Quantity | Shipping Container |
|------------------|----------|--------------------|
| RJL6015DPK-00-T0 | 360 pcs | Box (Tube) |

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